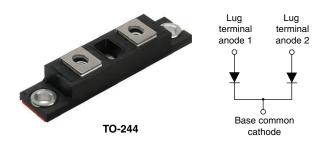
VS-HFA140NJ60CPbF

Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 167 A



PRIMARY CHARACTERISTICS				
I _F (maximum)	167 A			
V _R	600 V			
I _{F(DC)} at T _C	84 A at 100 °C			
Package	TO-244			
Circuit configuration	Two diodes common cathode			

FEATURES

- Very low Q_{rr} and t_{rr}
- UL approved file E222165
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Reduced snubbing

DESCRIPTION / APPLICATIONS

HEXFRED[®] diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and dl_F/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		600	V	
Continuous forward current I _F		$T_{C} = 25 \ ^{\circ}C$	167		
		T _C = 100 °C	84	А	
Single pulse forward current	I _{FSM}	Limited by junction temperature	400		
Non-repetitive avalanche energy	E _{AS}	L = 100 $\mu H,$ duty cycle limited by maximum $T_{\rm J}$	330	μJ	
Maximum power dissipation	P _D	$T_{C} = 25 \ ^{\circ}C$	310	W	
		T _C = 100 °C	132	vv	
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C	

ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-	
		I _F = 70 A		-	1.37	1.89	V
Maximum forward voltage	V _{FM}	I _F = 140 A	See fig. 1	-	1.58	2.1	
		I _F = 70 A, T _J = 125 °C		-	1.29	1.54	
Maximum reverse leakage current	I _{RM}	$T_J = 125 \text{ °C}, V_R = 480 \text{ V}$	See fig. 2	-	1.2	4	mA
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	140	250	pF
Series inductance	L _S	From top of terminal hole to mounting plane - 7.0 - n		nH			

Revision: 05-Jan-18

Document Number: 94051

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1







www.vishay.com

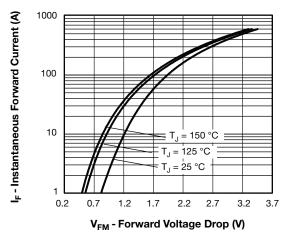
Vishay Semiconductors

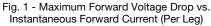
DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	\approx 200 A/µs, V _R = 30 V	-	33	-	ns	
Reverse recovery time (fig. 5)	t _{rr}	T _J = 25 °C	$l_{\rm F} = 70 {\rm A}$	-	80	120		
		T _J = 125 °C		-	140	220		
Peak recovery current (fig. 6)		$T_J = 25 \ ^\circ C$		-	8.5	15		
Feak recovery current (lig. 6)	I _{RRM}	T _J = 125 °C		-	14	25	A	
Bowerse receivery charge (fig. 7)			T _J = 25 °C	dI _F /dt = 200 A/µs V _R = 200 V	-	340	900	nC
Reverse recovery charge (fig. 7)	Q _{rr}	T _J = 125 °C		-	980	2300	no	
Peak rate of recovery current (fig. 8) dI _{(rec)M} /dt	dl (dt	T _J = 25 °C		-	300	-	A/µs	
	T _J = 125 °C		_	220	-	λγμs		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}	-55	-	150	°C
Thermal resistance, junction to case	per leg	P	-	-	0.38	°C/W K/W
merma resistance, junction to case	per module	– R _{thJC}	-	-	0.19	
Typical thermal resistance, case to heatsink		R _{thCS}		0.10	-	
Weight			-	68	-	g
weight			-	2.4	-	oz.
Mounting torque ⁽¹⁾			30 (3.4)	-	40 (4.6)	
Mounting torque center hole			12 (1.4)	-	18 (2.1)	lbf · in (N · m)
Terminal torque			30 (3.4)	-	40 (4.6)	(
Vertical pull			-	-	80	lbf∙in
2" lever pull			-	-	35	חוייוטו

Note

(1) Mounting surface must be smooth, flat, free or burrs or other protrusions. Apply a thin even film or thermal grease to mounting surface. Gradually tighten each mounting bolt in 5 - 10 lbf · in steps until desired or maximum torque limits are reached





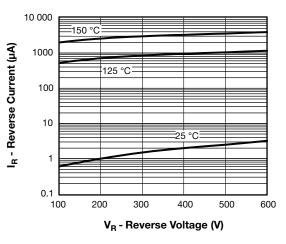


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

Revision: 05-Jan-18

2

Document Number: 94051

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



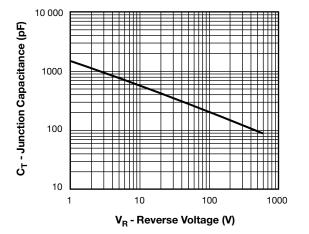


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

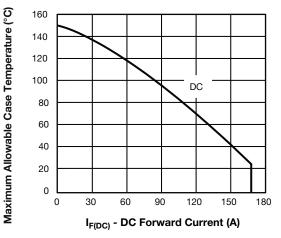


Fig. 4 - Maximum Allowable Case Temperature vs. DC Forward Current (Per Leg)

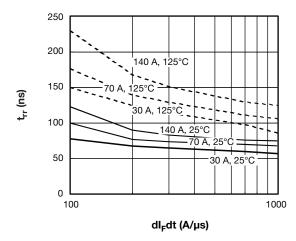


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

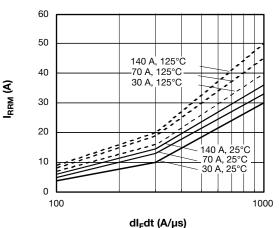


Fig. 6 - Typical Recovery Current vs. dl_F/dt (Per Leg)

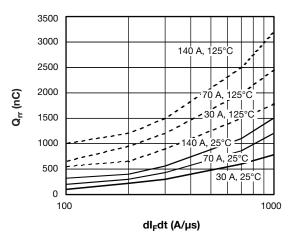


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

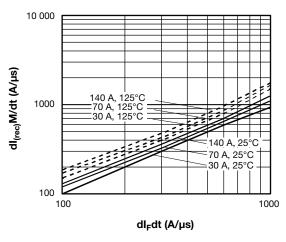


Fig. 8 - Typical dl_{(rec)M}/dt vs. dl_F/dt (Per Leg)

Revision: 05-Jan-18

3

Document Number: 94051

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

VS-HFA140NJ60CPbF

Vishay Semiconductors

VS-HFA140NJ60CPbF

10

Vishay Semiconductors

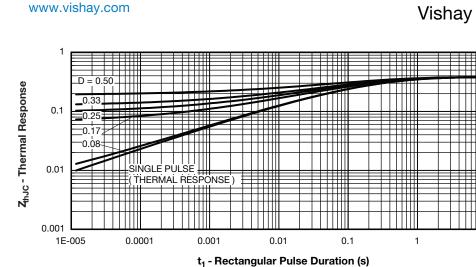


Fig. 9 - Maximum Thermal Impedance Z_{thJC} Characteristics

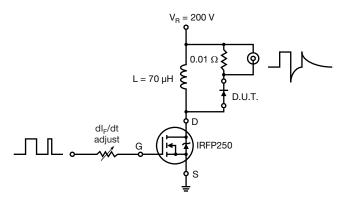


Fig. 10 - Reverse Recovery Parameter Test Circuit

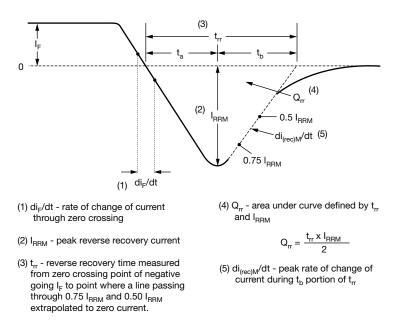


Fig. 11 - Reverse Recovery Waveform and Definitions

Revision: 05-Jan-18	4	Document Number: 94051
For technical questions within your regior	n: <u>DiodesAmericas@vishay.com</u> , <u>DiodesAsia@vishay.cc</u>	om, <u>DiodesEurope@vishay.com</u>
	GE WITHOUT NOTICE. THE PRODUCTS DESCRIBED CIFIC DISCLAIMERS, SET FORTH AT www.vishav.con	



VS-HFA140NJ60CPbF

Vishay Semiconductors

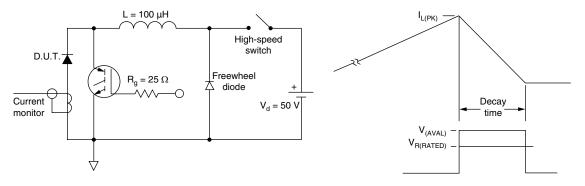
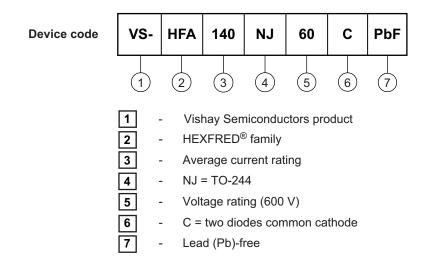


Fig. 12 - Avalanche Test Circuit and Waveforms

ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95021		

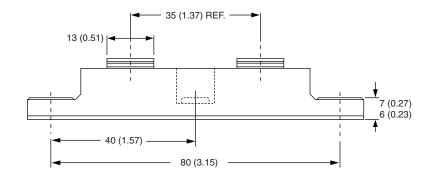


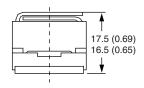


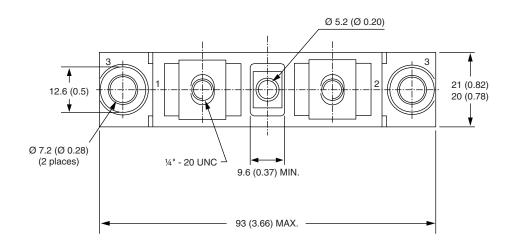
Vishay Semiconductors

TO-244

DIMENSIONS in millimeters (inches)









Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.